

PRELIMINARY

SFT10000/3

SOLID STATE DEVICES, INC. 14830 Valley View Blvd * La Mirada, Ca 90638 Phone: (562) 404-7855 * Fax: (562) 404-1773

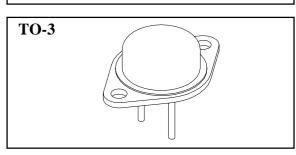
DESIGNER'S DATA SHEET

APPLICATION NOTES:

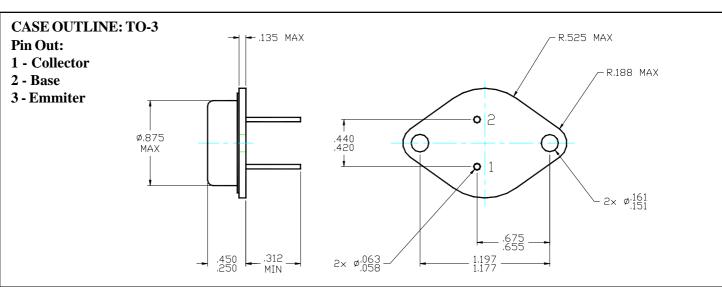
SFT10000 Darlington Transistor is direct replacement of Motorolla MJ 10000. It is designed for high voltage, high speed, power switching in inductive circuits where fall time is critical. It is particularly suited for line operated switchmode applications such as:

- Switching Regulators
- Inverters
- **Solenoid and Relay Drives**
- **Motor Controls**
- **Deflection Cirsuits.**

20 AMP 350 VOLTS NPN DARLINGTON **TRANSISTOR**



MAXIMUM RATINGS		SYMBOL	VALUE	UNITS
Collector-Emitter Voltage		V _{CEO}	350	Volts
Collector-Emitter Voltage		V_{CEV}	450	Volts
Emitter-Base Voltage		${ m V_{EB}}$	8	Volts
Collector Current	Continuous Peak	I_{C} I_{CM}	20 30	Amps
Base Current		I_B	2.5	Amps
Total Device Dissipation Derate above 25°C	@ $T_C = 25^{\circ}C$ @ $T_C = 100^{\circ}C$	P_{D}	175 100 1	W W W/°C
Operating and Storage Temperature		T_{J}, T_{STG}	-65 to +200	°C
Thermal Resistance, Junction to Case		$R_{ heta JC}$	1	°C/W



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ELECTI					
	ELECTRICAL CHARACTERISTICS		MIN	MAX	UNITS
		V _{CEO(sus)}	350	-	V _{DC}
		V _{CEX(sus)}	400 275	-	V _{DC}
		I _{CBO}	-	0.25 5.0	mA _{DC}
Collector Cutoff Current $(V_{CEV} = Rated\ V_{CEV},\ R_{BE} = 50\Omega,\ T_C = 100^{\circ}C)$		I_{CEV}	-	5	mA _{DC}
		I_{EBO}	-	150	mA _{DC}
$\begin{array}{ll} \textbf{DC Current Gain*} & I_C = 5A_{DC} \\ (V_{CE} = 5V_{DC}) & I_C = 10A_{DC} \end{array}$		$\mathbf{H}_{\mathbf{FE}}$	50 40	600 400	
$\label{eq:collector-Emitter Saturation Voltage*} \begin{split} I_C &= 10 A_{DC}, \ I_B = 400 m A_{DC}, T_C = 25^{\circ}C \\ I_C &= 20 A_{DC}, \ I_B = 1 A_{DC}, T_C = 25^{\circ}C \\ I_C &= 10 A_{DC}, \ I_B = 400 m A_{DC}, T_C = 100^{\circ}C \end{split}$		V _{CE(SAT)}	- - -	1.9 3.0 2.0	V _{DC}
$\begin{tabular}{lll} \textbf{Base-Emitter Saturation Voltage*} & & & & & & & & & & \\ (I_C = 10A_{DC}, I_B = 400mA_{DC}) & & & & & & \\ & & & & & & & & \\ & & & & & & & \\ & & & & & & & \\ & & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\ & & \\ & & & \\ & $		V _{BE} (SAT)	-	2.5 2.5	V _{DC}
		$\mathbf{V_F}$	-	5.0	V _{DC}
		${ m H_{FE}}$	10	-	
Output Capacitance $(V_{CB} = 30V_{DC}, I_E = 0A_{DC}, f = 2.0MHz)$		Cob	100	325	pf
Delay Time		t _d	-	0.2	μs
Rise Time	$V_{CC} = 250V_{DC}$, $I_{C} = 10A_{DC}$, $I_{B1} = 400mA_{DC}$, $V_{BE(off)} = 5V_{DC}$	t _r	-	0.6	μs
Storage Time	$t_{\rm P} = 50\mu {\rm sec}$, $V_{\rm BE}(01) = 3 {\rm VDC}$	t_s	-	3.5	μs
Fall Time		$\mathbf{t_f}$	-	2.4	μs
Storage Time	$I_C = 10A(pk), V_{CLAMP} = Rated V_{CEX},$	t_{sv}	-	5.5	μs
Crossover Time	$I_{B1} = 400 \text{mA}, V_{BE(off)} = 5V_{DC}, T_C = 100^{\circ}\text{C}$	t_c	-	3.7	μs

^{*}Pulse Test: Pulse Width = 300us, Duty Cycle = 2%